1N582x

LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCTS CHARACTERISTICS

$I_{F(AV)}$	**3 A**
V_{RRM}	**40 V**
T_j	**150°C**
V_F **(max)**	**0.475 V**

DO-201AD

FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters. Packaged in DO-201AD these devices are intended for use in low voltage, high frequency inverters, free wheeling, polarity protection and small battery chargers.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value			Unit
			1N5820	1N5821	1N5822	
V_{RRM}	Repetitive peak reverse voltage		20	30	40	V
$I_{F(RMS)}$	RMS forward current		10			A
$I_{F(AV)}$	Average forward current	T_L = 100°C δ = 0.5			3	A
		T_L = 110°C δ = 0.5	3	3		A
I_{FSM}	Surge non repetitive forward current	tp = 10 ms Sinusoidal	80			A
P_{ARM}	Repetitive peak avalanche power	tp = 1µs Tj = 25°C	1700			W
T_{stg}	Storage temperature range		- 65 to + 150			°C
Tj	Maximum operating junction temperature *		150			°C
dV/dt	Critical rate of rise of reverse voltage		10000			V/µs

* : $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th\ (j-a)}$	Junction to ambient	Lead length = 10 mm	80	°C/W
$R_{th\ (j-l)}$	Junction to lead	Lead length = 10 mm	25	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		1N5820	1N5821	1N5822	Unit
I_R *	Reverse leakage current	Tj = 25°C	$V_R = V_{RRM}$	2	2	2	mA
		Tj = 100°C		20	20	20	mA
V_F *	Forward voltage drop	Tj = 25°C	I_F = 3 A	0.475	0.5	0.525	V
		Tj = 25°C	I_F = 9.4 A	0.85	0.9	0.95	V

Pulse test : * tp = 380 µs, δ < 2%

To evaluate the conduction losses use the following equations :
$P = 0.33 \times I_{F(AV)} + 0.035\ I_{F^2(RMS)}$ for 1N5820 / 1N5821
$P = 0.33 \times I_{F(AV)} + 0.060\ I_{F^2(RMS)}$ for 1N5822

Fig. 1: Average forward power dissipation versus average forward current (1N5820/1N5821).

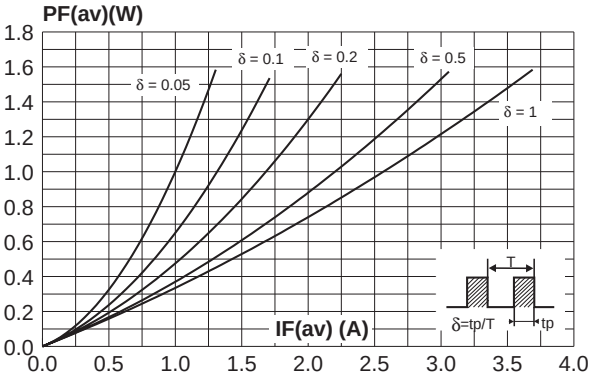


Fig. 2: Average forward power dissipation versus average forward current (1N5822).

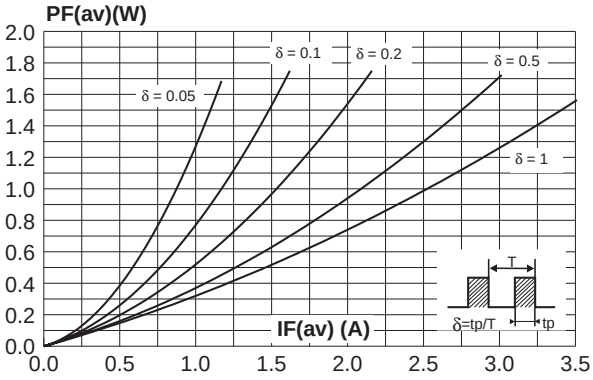


Fig. 3: Normalized avalanche power derating versus pulse duration.

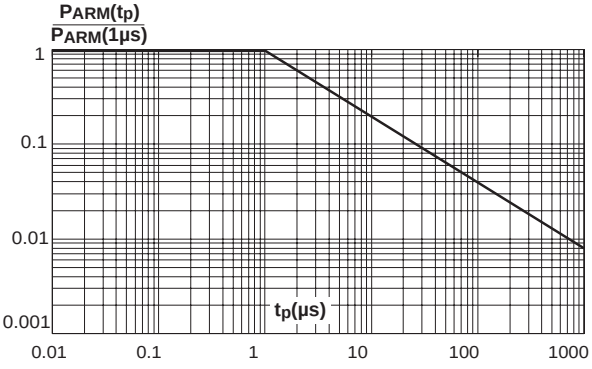


Fig. 4: Normalized avalanche power derating versus junction temperature.

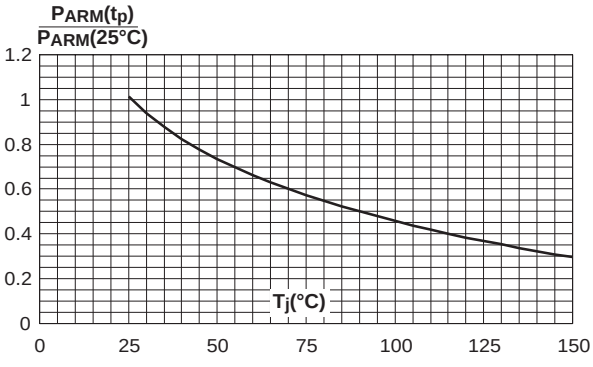


Fig. 5-1: Average forward current versus ambient temperature (δ=0.5) (1N5820/1N5821).

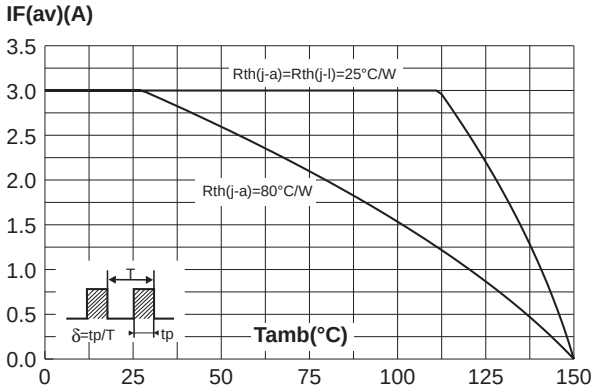


Fig. 5-2: Average forward current versus ambient temperature (δ=0.5) (1N5822).

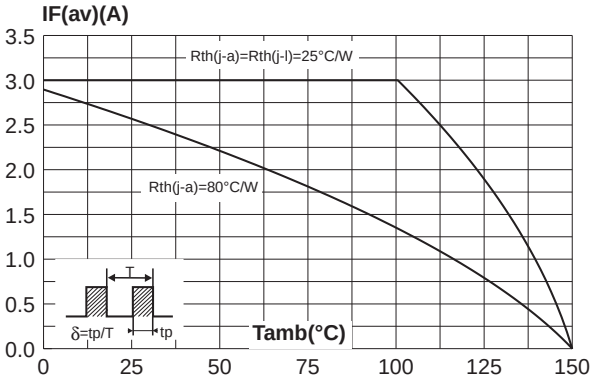


Fig. 6-1: Non repetitive surge peak forward current versus overload duration (maximum values) (1N5820/1N5821).

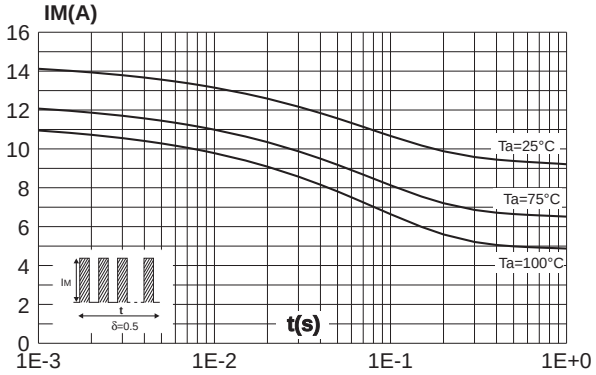


Fig. 6-2: Non repetitive surge peak forward current versus overload duration (maximum values) (1N5822).

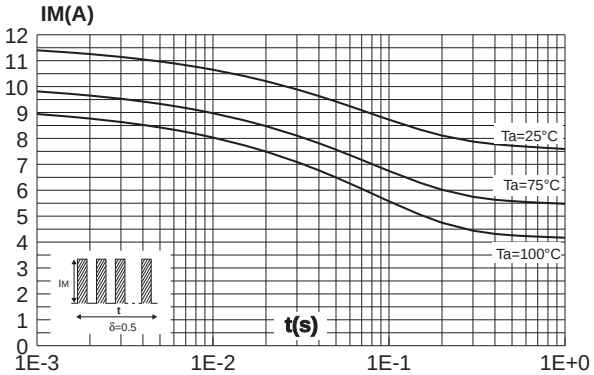


Fig. 7: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, e(Cu)=35mm, recommended pad layout).

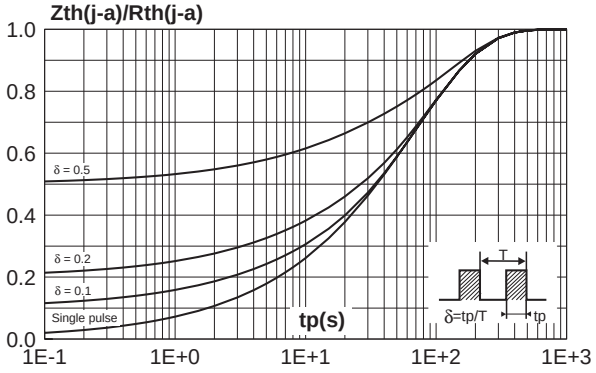


Fig. 8: Junction capacitance versus reverse voltage applied (typical values).

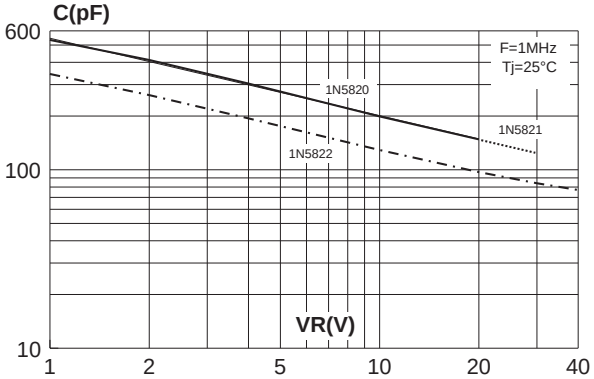


Fig. 9-1: Reverse leakage current versus reverse voltage applied (typical values) (1N5820/1N5821).

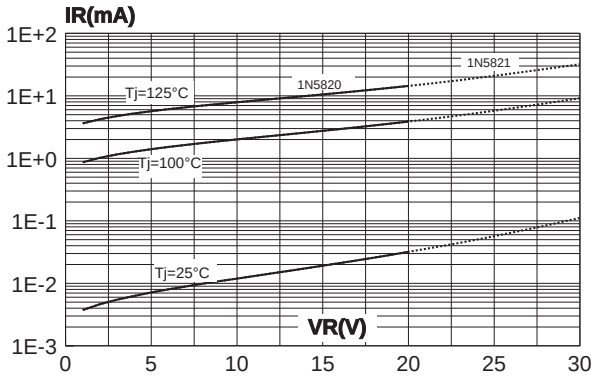


Fig. 9-2: Reverse leakage current versus reverse voltage applied (typical values) (1N5822).

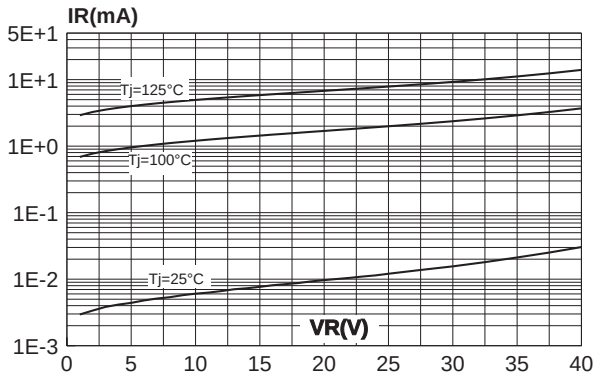


Fig. 10-1: Forward voltage drop versus forward current (typical values) (1N5820/1N5821).

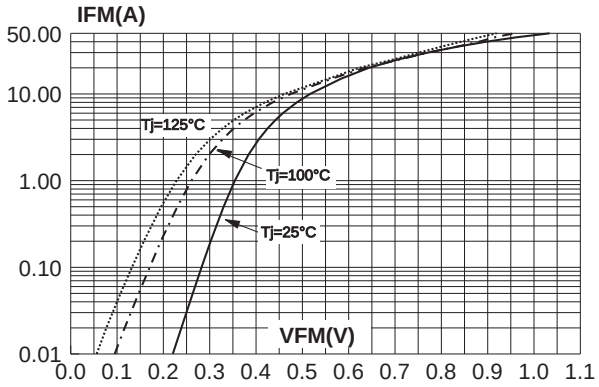


Fig. 10-2: Forward voltage drop versus forward current (typical values) (1N5822).

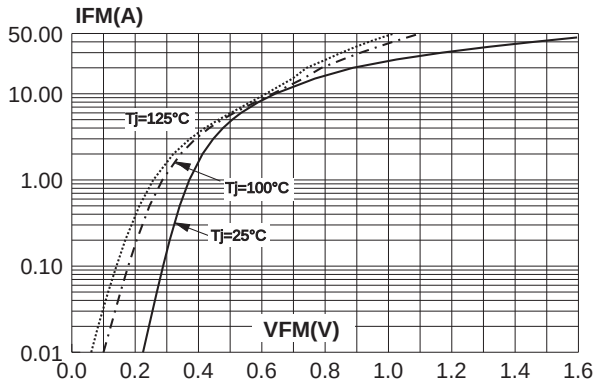
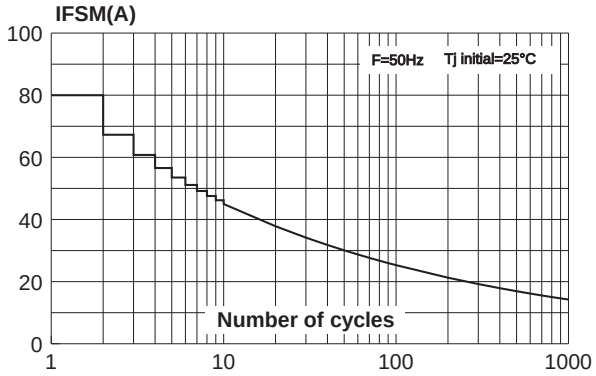
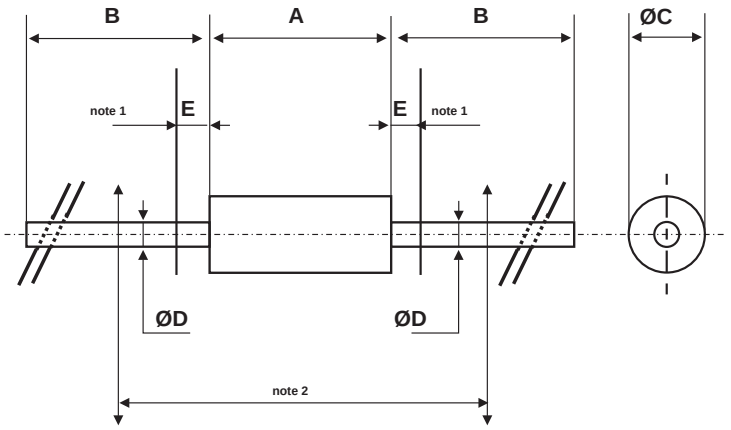


Fig. 11: Non repetitive surge peak forward current versus number of cycles.



PACKAGE MECHANICAL DATA

DO-201AD plastic



REF.	DIMENSIONS				NOTES
	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A		9.50		0.374	1 - The lead diameter ♠ D is not controlled over zone E 2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59"(15 mm)
B	25.40		1.000		
♠ C		5.30		0.209	
♠ D		1.30		0.051	
E		1.25		0.049	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
1N582x	Part number cathode ring	DO-201AD	1.12g	600	Ammopack
1N582xRL	Part number cathode ring	DO-201AD	1.12g	1900	Tape & reel

- EPOXY MEETS UL94,V0

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers ***category:***

Click to view products by STMicroelectronics ***manufacturer:***

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573